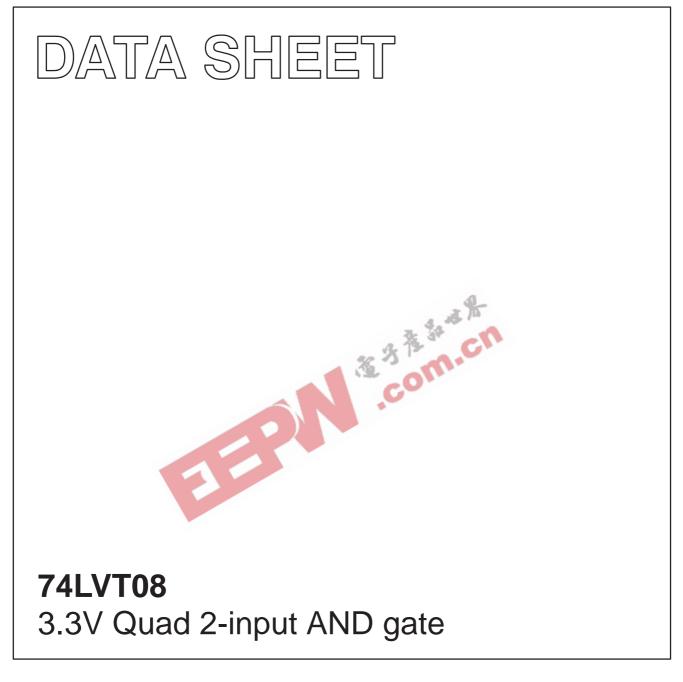
INTEGRATED CIRCUITS



Product specification

IC24 Data Handbook

1996 May 29

PHILIPS PHILIPS

74LVT08

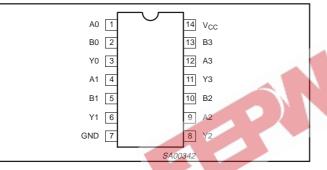
QUICK REFERENCE DATA

SYMBOL	PARAMETER	TEST CONDITIONS T _{amb} = 25°C; GND = 0V	TYPICAL	UNIT
t _{PLH} t _{PHL}	Propagation delay An or Bn to Yn	$C_L = 50 pF;$ $V_{CC} = 3.3 V$	3.0 3.4	ns
C _{IN}	Input capacitance	$V_{I} = 0V \text{ or } 3.0V$	4	pF
I _{CCL}	Total supply current	Outputs Low; $V_{CC} = 3.6V$	1	mA

ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	PKG. DWG. #
14-Pin Plastic SO	–40°C to +85°C	74LVT08 D	74LVT08 D	SOT108-1
14-Pin Plastic SSOP	–40°C to +85°C	74LVT08 DB	74LVT08 DB	SOT337-1
14-Pin Plastic TSSOP	–40°C to +85°C	74LVT08 PW	74LVT08PW DH	SOT402-1

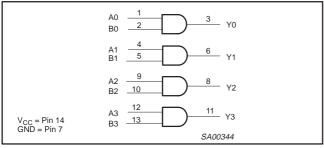
PIN CONFIGURATION



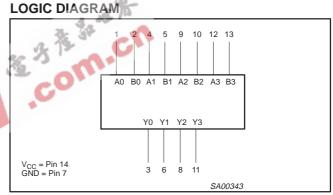
PIN DESCRIPTION

PIN NUMBER	SYMBOL	NAME AND FUNCTION
1, 2, 4, 5, 9, 10, 12, 13	An-Bn	Data inputs
3, 6, 8, 11	Yn	Data outputs
7	GND	Ground (0V)
14	V _{CC}	Positive supply voltage

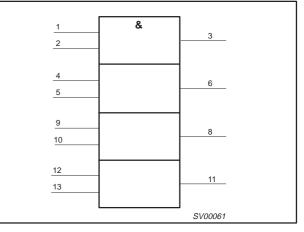
LOGIC SYMBOL



LOGIC DIAGRAM



LOGIC SYMBOL (IEEE/IEC)



74LVT08

FUNCTION TABLE

INPUTS		OUTPUT
Dna	Dnb	Qn
L	L	L
L	Н	L
Н	L	L
Н	Н	Н

NOTES:

H = High voltage level

L = Low voltage level

ABSOLUTE MAXIMUM RATINGS^{1, 2}

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V _{CC}	DC supply voltage		-0.5 to +4.6	V
I _{IK}	DC input diode current	V ₁ < 0	-50	mA
VI	DC input voltage ³	4.15 14	-0.5 to +7.0	V
I _{OK}	DC output diode current	V _O < 0	-50	mA
V _{OUT}	DC output voltage ³	Output in Off or High state	-0.5 to +7.0	V
		Output in High state	-32	
I _{OUT} D	DC output current	Output in Low state	64	mA
T _{stg}	Storage temperature range		–65 to 150	°C

NOTES:

Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150°C.

3. The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER		LIMITS		
STWBUL	FARAWETER	MIN	MAX	UNIT	
V _{CC}	DC supply voltage		3.6	V	
VI	Input voltage		5.5	V	
V _{IH}	High-level input voltage			V	
V _{IL}	Low-level Input voltage		0.8	V	
I _{ОН}	High-level output current		-20	mA	
I _{OL}	Low-level output current		32	mA	
Δt/Δv	Input transition rise or fall rate; Outputs enabled		10	ns/V	
T _{amb}	Operating free-air temperature range		+85	°C	

74LVT08

DC ELECTRICAL CHARACTERISTICS

Over recommended operating conditions Voltages are referenced to GND (ground = 0V)

LIMITS SYMBOL PARAMETER **TEST CONDITIONS** Temp = -40° C to $+85^{\circ}$ C UNIT TYP¹ MIN MAX V $V_{CC} = 2.7V; I_{IK} = -18mA$ VIK Input clamp voltage -1.2 V_{CC}-0.2 V_{CC} = 2.7 to 3.6V; I_{OH} = -100 μ A VOH High-level output voltage $V_{CC} = 2.7V; I_{OH} = -6mA$ 2.4 V $V_{CC} = 3.0V; I_{OH} = -20mA$ 2.0 $V_{CC} = 2.7V; I_{OL} = 100\mu A$ 0.2 V V_{CC} = 2.7V; I_{OL} = 24mA 0.5 VOL Low-level output voltage $V_{CC} = 3.0V; I_{OL} = 32mA$ 0.5 $V_{CC} = 0 \text{ or } 3.6V; V_{I} = 5.5V$ 10 Input leakage current ł_l μΑ JE 14 $V_{CC} = 3.6V; V_I = V_{CC} \text{ or } GND$ ±1 $V_{CC} = 0V; V_1 \text{ or } V_0 = 0 \text{ to } 4.5V$ **I**OFF Output off current ±100 μΑ $V_{CC} = 3.6V$; Outputs High, $V_{I} = GND$ or ICCH 0.02 V_{CC} , $I_{O} = 0$ Quiescent supply current mΑ $V_{CC} = 3.6V$; Outputs Low, $V_1 = GND$ or V_{CC} , 1 2 I_{CCL} $I_{O} = 0$ $V_{CC} = 3V$ to 3.6V; One input at V_{CC} -0.6V, μΑ Additional supply current per input pin² 0.2 ΔI_{CC} Other inputs at V_{CC} or GND $V_{l} = 3V \text{ or } 0$ CI Input capacitance 4 pF Co Output capacitance $V_{\Omega} = 3V \text{ or } 0$ 10 pF

NOTES:

1. All typical values are at $V_{CC} = 3.3V$ and $T_{amb} = 25^{\circ}C$. 2. This is the increase in supply current for each input at the specificed voltage level other than V_{CC} or GND.

AC CHARACTERISTICS

GND = 0V; $t_R = t_F = 2.5ns$; $C_L = 50pF$, $R_L = 500\Omega$; $T_{amb} = -40^{\circ}C$ to +85°C.

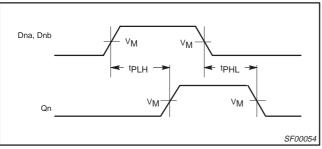
			LIMITS				
SYMBOL	PARAMETER	WAVEFORM	Vcc	$= 3.3 V \pm 0.0$.3V	$V_{CC} = 2.7 V$	UNIT
			MIN	TYP ¹	MAX	MAX	
t _{PLH} t _{PHL}	Propagation delay An or Bn to Yn	1	1.0 1.0	3.0 3.4	3.9 4.6	4.7 4.8	ns

NOTE:

1. All typical values are at $V_{CC} = 3.3V$ and $T_{amb} = 25^{\circ}C$.

AC WAVEFORMS

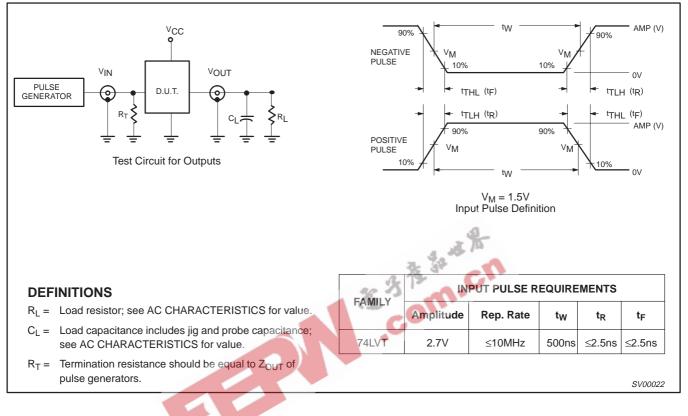
 $V_{M} = 1.5V, V_{IN} = GND \text{ to } 2.7V$

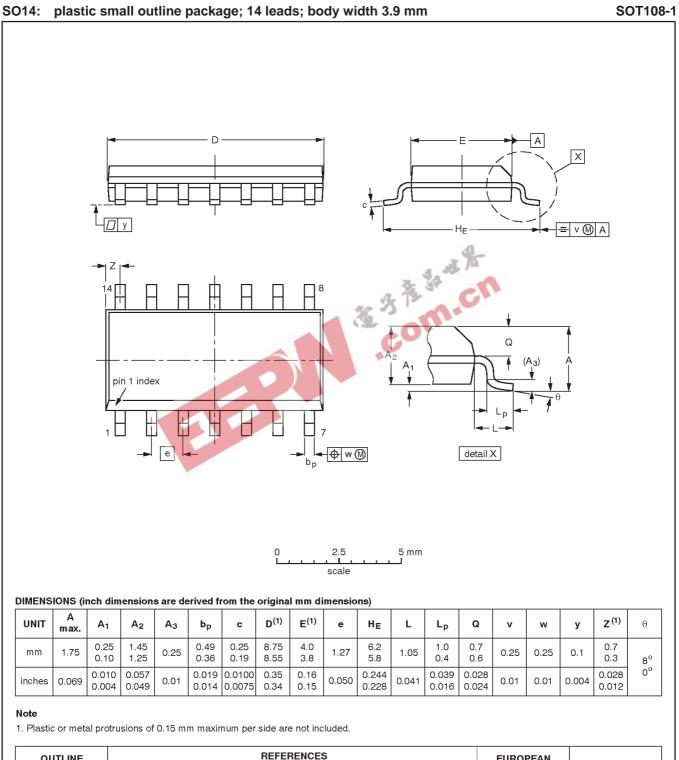


Waveform 1. Propagation Delay for Non-Inverting Outputs

74LVT08

TEST CIRCUIT AND WAVEFORMS





6

MS-012AB

1996 May 29

SOT108-1

076E06S

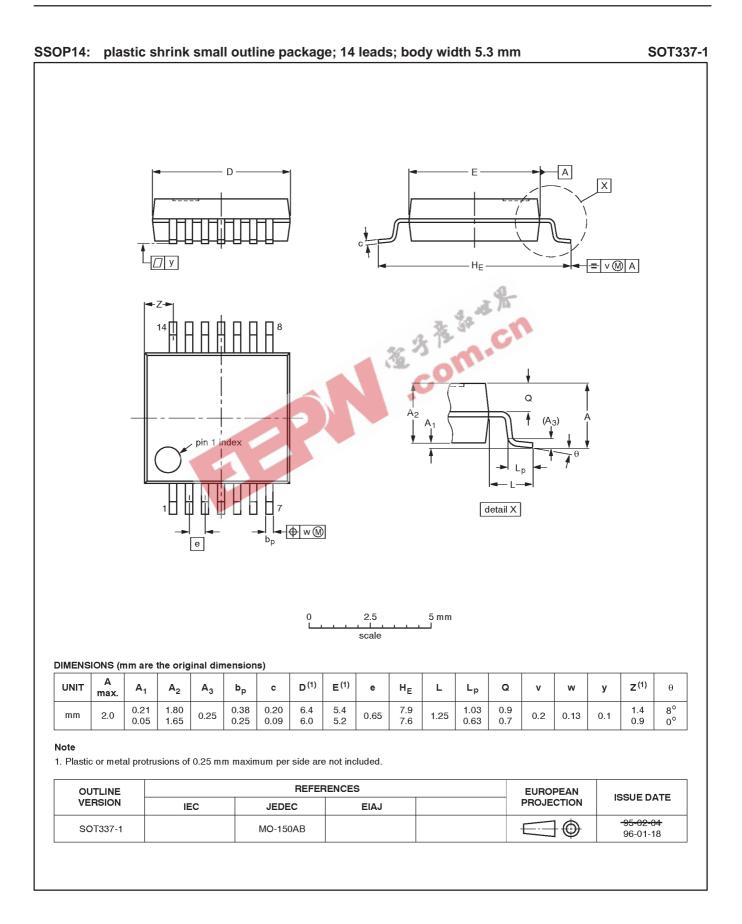
95-01-23

97-05-22

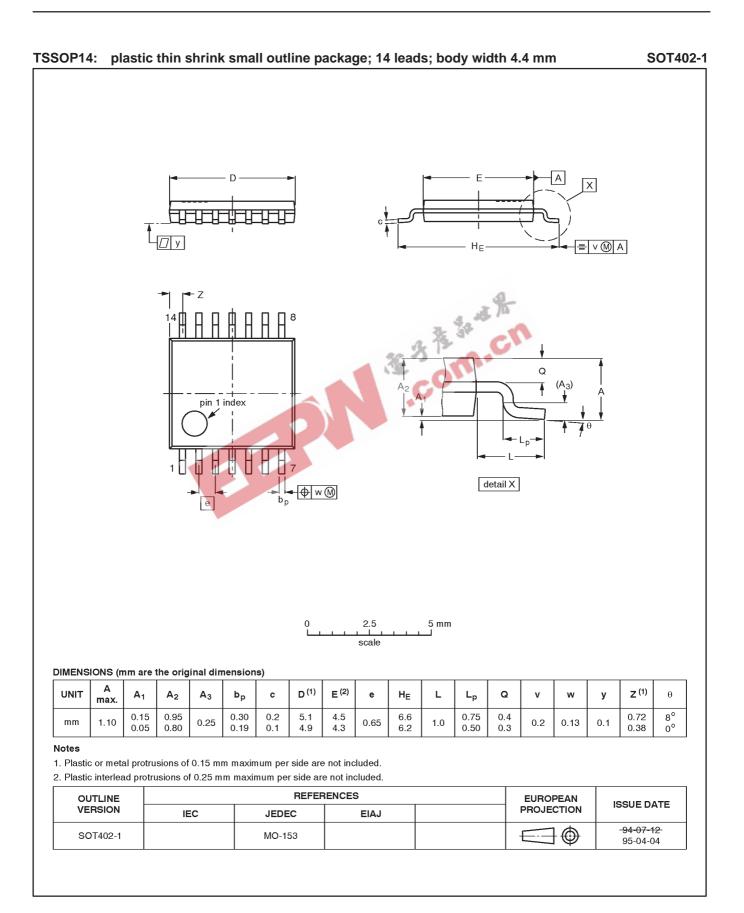
 \odot

F

74LVT08



74LVT08

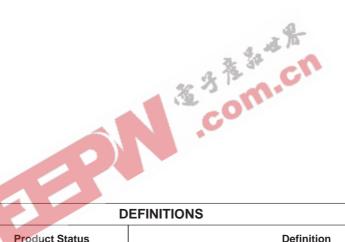


74LVT08

NOTES



74LVT08



DEFINITIONS				
Data Sheet Identification	Product Status	Definition		
Objective Specification Formative or in Design This data sheet contains the design target or goal specifications for product development. S may change in any manner without notice.		This data sheet contains the design target or goal specifications for product development. Specifications may change in any manner without notice.		
		This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.		
Product Specification	Full Production	This data sheet contains Final Specifications. Philips Semiconductors reserves the right to make changes at any time without notice, in order to improve design and supply the best possible product.		

Philips Semiconductors and Philips Electronics North America Corporation reserve the right to make changes, without notice, in the products, including circuits, standard cells, and/or software, described or contained herein in order to improve design and/or performance. Philips Semiconductors assumes no responsibility or liability for the use of any of these products, conveys no license or title under any patent, copyright, or mask work right to these products, and makes no representations or warranties that these products are free from patent, copyright, or mask work right infringement, unless otherwise specified. Applications that are described herein for any of these products are for illustrative purposes only. Philips Semiconductors makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

LIFE SUPPORT APPLICATIONS

Philips Semiconductors and Philips Electronics North America Corporation Products are not designed for use in life support appliances, devices, or systems where malfunction of a Philips Semiconductors and Philips Electronics North America Corporation Product can reasonably be expected to result in a personal injury. Philips Semiconductors and Philips Electronics North America Corporation customers using or selling Philips Semiconductors and Philips Electronics North America Corporation so at their own risk and agree to fully indemnify Philips Semiconductors and Philips Electronics North America Corporation for any damages resulting from such improper use or sale.

Philips Semiconductors 811 East Arques Avenue P.O. Box 3409 Sunnyvale, California 94088–3409 Telephone 800-234-7381 Philips Semiconductors and Philips Electronics North America Corporation register eligible circuits under the Semiconductor Chip Protection Act. © Copyright Philips Electronics North America Corporation 1996 All rights reserved. Printed in U.S.A.

> (print code) Document order number:

Date of release: July 1994

9397-750-04845